Power MOSFET

-20 V, -8.2 A, Single P-Channel, 2.0x2.0x0.55 mm μCool™ UDFN Package

Features

- UDFN Package with Exposed Drain Pads for Excellent Thermal Conduction
- Low Profile UDFN 2.0x2.0x0.55 mm for Board Space Saving
- Ultra Low R_{DS(on)}
- ESD Diode-Protected Gate
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Optimized for Power Management Applications for Portable Products, such as Cell Phones, Media Tablets, PMP, DSC, GPS, and Others
- Battery Switch
- High Side Load Switch

MAXIMUM RATINGS (T_J = 25°C unless otherwise stated)

Parameter		Symbol	Value	Unit	
Drain-to-Source Voltage		V _{DSS}	-20	V	
Gate-to-Source Vol	tage		V_{GS}	±8.0	V
Continuous Drain	Steady State	T _A = 25°C	I _D	-8.2	Α
Current (Note 1) Continuous Drain	State	T _A = 85°C		-5.9	
Current (Note 1)	t ≤ 5 s	T _A = 25°C		-12.2	
Power Dissipa- tion (Note 1)	Steady State	T _A = 25°C	P _D	1.7	W
	t ≤ 5 s	T _A = 25°C	1	3.8	
Continuous Drain	Steady State	T _A = 25°C	I _D	-5.1	Α
Current (Note 2)	State	T _A = 85°C		-3.7	
Power Dissipation (Note 2) T _A = 25°C		P _D	0.7	W	
Pulsed Drain Current tp = 10 μs		I _{DM}	-25	Α	
Operating Junction and Storage Temperature		T _J , T _{STG}	-55 to 150	°C	
ESD (HBM, JESD22-A114)		V _{ESD}	2000	V	
Source Current (Body Diode) (Note 2)		I _S	-1.7	Α	
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)		TL	260	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

- Surface Mounted on FR4 Board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
- Surface-mounted on FR4 board using the minimum recommended pad size of 30 mm², 2 oz. Cu.

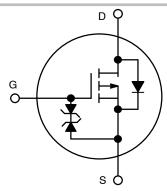


ON Semiconductor®

http://onsemi.com

MOSFET

V _{(BR)DSS}	R _{DS(on)} MAX	I _D MAX	
	18 mΩ @ –4.5 V		
-20 V	25 mΩ @ -2.5 V	_8.2 A	
	50 mΩ @ –1.8 V	-0.27	
	90 mΩ @ –1.5 V		



P-Channel MOSFET

MARKING DIAGRAM



UDFN6 (μCOOL™) CASE 517BG



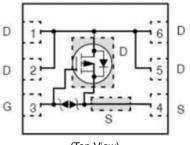
AC = Specific Device Code

M = Date Code

= Pb-Free Package

(*Note: Microdot may be in either location)

PIN CONNECTIONS



(Top View)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient – Steady State (Note 3)	$R_{\theta JA}$	72	
Junction-to-Ambient – $t \le 5 s$ (Note 3)	$R_{\theta JA}$	33	°C/W
Junction-to-Ambient – Steady State min Pad (Note 4)	$R_{\theta JA}$	189	

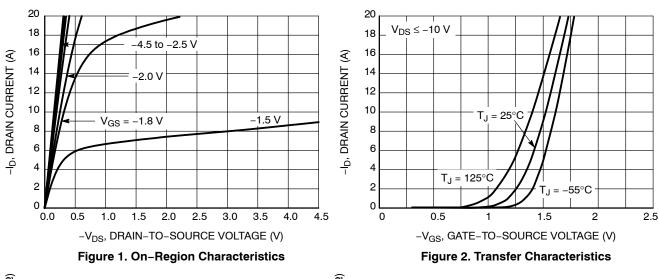
- 3. Surface-mounted on FR4 board using 1 in sq pad size (Cu area = 1.127 in sq [2 oz] including traces).
 4. Surface-mounted on FR4 board using the minimum recommended pad size of 30 mm², 2 oz. Cu.

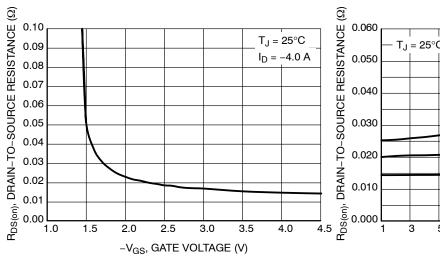
ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

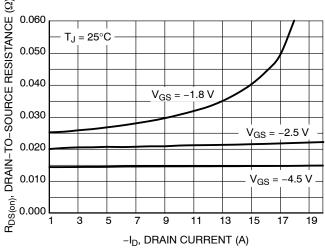
Parameter	Symbol	Test Co	ndition	Min	Тур	Max	Units
OFF CHARACTERISTICS		•		•			
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	V _{GS} = 0 V, I	_D = -250 μA	-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J	I _D = -250 μΑ	, ref to 25°C		+10		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V, V _{DS} = -20 V	T _J = 25°C			-1.0	μΑ
Gate-to-Source Leakage Current	I _{GSS}	V _{DS} = 0 V, V	_{GS} = ±5.0 V			±5	μΑ
ON CHARACTERISTICS (Note 5)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}$,	I _D = -250 μA	-0.4		-1.0	V
Negative Threshold Temp. Coefficient	$V_{GS(TH)}/T_J$				3.0		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = -4.5 \	/, I _D = -7.0 A		14.6	18	mΩ
		V _{GS} = −2.5 \	/, I _D = −5.0 A		19	25	
		V _{GS} = −1.8 \	/, I _D = −3.0 A		25	50	
		V _{GS} = −1.5 \	/, I _D = −1.0 A		40	90	
Forward Transconductance	9FS	V _{DS} = −5 V	, I _D = -3.0 A		40		S
CHARGES, CAPACITANCES & GATE	RESISTANCE						
Input Capacitance	C _{ISS}				2240		pF
Output Capacitance	C _{OSS}		f = 1 MHz, –15 V		240		
Reverse Transfer Capacitance	C _{RSS}	. D3			210		
Total Gate Charge	Q _{G(TOT)}				28		nC
Threshold Gate Charge	Q _{G(TH)}	V _{GS} = -4.5 V,	$V_{DS} = -15 \text{ V};$		1.0		
Gate-to-Source Charge	Q _{GS}	V _{GS} = -4.5 V, I _D = -	-4.0 A		2.9		
Gate-to-Drain Charge	Q_GD				8.8		
SWITCHING CHARACTERISTICS, VG	S = 4.5 V (Note 6)			•			
Turn-On Delay Time	t _{d(ON)}				8.6		ns
Rise Time	t _r	VGS = -4.5 V.	Vnn = -15 V.		15		
Turn-Off Delay Time	t _{d(OFF)}	V _{GS} = -4.5 V, I _D = -4.0 A	$R_{G} = 1 \Omega$		150		
Fall Time	t _f				88		
DRAIN-SOURCE DIODE CHARACTER	RISTICS			•			
Forward Diode Voltage	V_{SD}	V _{GS} = 0 V,	T _J = 25°C		0.63	1.0	V
		I _S = -1.0 A	T _J = 125°C		0.50		
Reverse Recovery Time	t _{RR}		•		26.1		ns
Charge Time	t _a	V _{GS} = 0 V, dls	/dt = 100 A/us.		10.2		
Discharge Time	t _b	I _S = -1.0 A 15.9					
Reverse Recovery Charge	Q _{RR}				12		nC

- 5. Pulse Test: pulse width \leq 300 μ s, duty cycle \leq 2%.
- 6. Switching characteristics are independent of operating junction temperatures.

TYPICAL CHARACTERISTICS







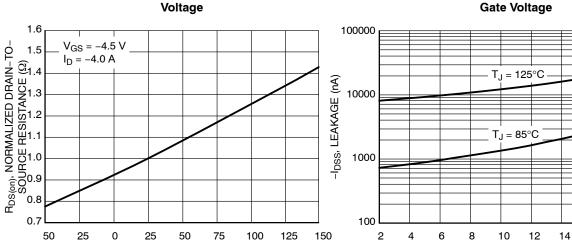
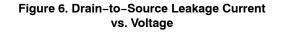


Figure 4. On-Resistance vs. Drain Current and Gate Voltage



-V_{DS}, DRAIN-TO-SOURCE VOLTAGE (V)

16

18

20

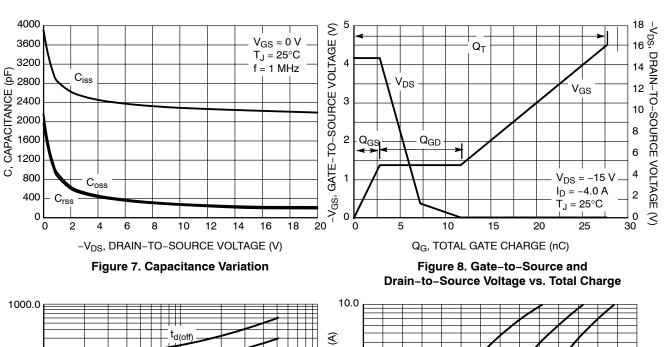
T_J, JUNCTION TEMPERATURE (°C)

Figure 5. On-Resistance Variation with

Temperature

Figure 3. On-Resistance vs. Gate-to-Source

TYPICAL CHARACTERISTICS



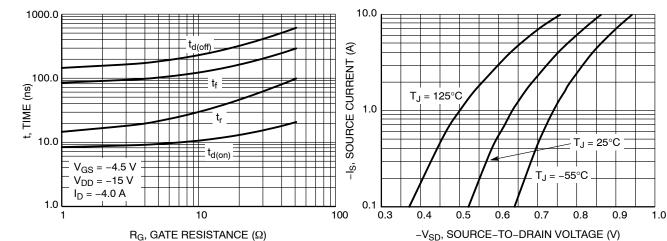


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

Figure 11. Threshold Voltage

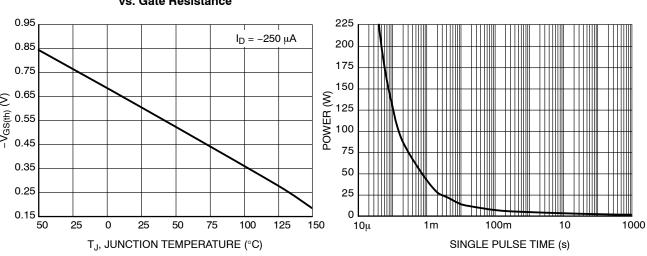


Figure 10. Diode Forward Voltage vs. Current

Figure 12. Single Pulse Maximum Power Dissipation

TYPICAL CHARACTERISTICS

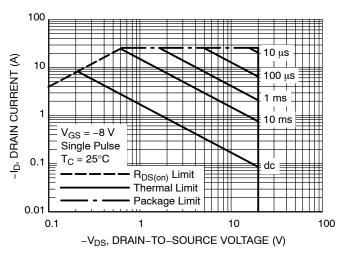


Figure 13. Maximum Rated Forward Biased Safe Operating Area

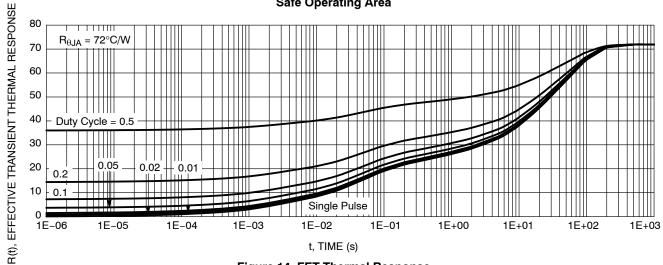


Figure 14. FET Thermal Response

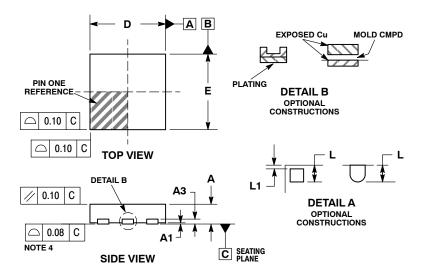
DEVICE ORDERING INFORMATION

Device	Package	Shipping [†]
NTLUS3A18PZTAG	UDFN6 (Pb-Free)	3000 / Tape & Reel
NTLUS3A18PZTBG	UDFN6 (Pb-Free)	3000 / Tape & Reel
NTLUS3A18PZTCG	UDFN6 (Pb-Free)	3000 / Tape & Reel

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

PACKAGE DIMENSIONS

UDFN6 2x2, 0.65P CASE 517BG **ISSUE A**

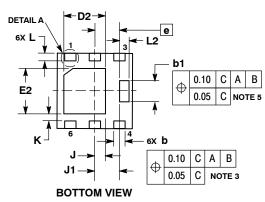


NOTES:

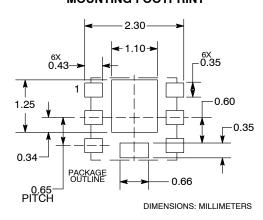
- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
 DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM TERMINAL
- COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS THE TERMINALS
- CENTER TERMINAL LEAD IS OPTIONAL. CENTER TERMINAL
- IS CONNECTED TO TERMINAL LEAD # 4.

 6. LEADS 1, 2, 5 AND 6 ARE TIED TO THE FLAG.

,	1, 2, 0 / 1110	07111E 11E	
	MILLIMETERS		
DIM	MIN	MAX	
Α	0.45	0.55	
A1	0.00	0.05	
A3	0.13 REF		
b	0.25	0.35	
b1	0.51	0.61	
D	2.00 BSC		
D2	1.00	1.20	
E	2.00 BSC		
E2	1.10	1.30	
е	0.65 BSC		
K	0.15 REF		
J	0.27 BSC		
J1	0.65 BSC		
L	0.20	0.30	
L1		0.10	
L2	0.20	0.30	



RECOMMENDED **MOUNTING FOOTPRINT***



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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